

# SN54HC36, SN74HC36 QUADRUPLE 2-INPUT POSITIVE-NOR GATES

D2684, DECEMBER 1982 — REVISED SEPTEMBER 1987

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs
- Dependable Texas Instruments Quality and Reliability

## description

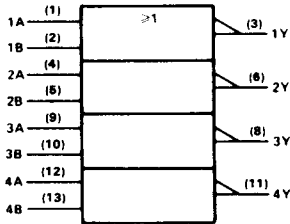
These devices contain four independent 2-input NOR gates. They perform the Boolean functions  $Y = A + B$  or  $Y = A \cdot B$  in positive logic.

The SN54HC36 is characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN74HC36 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

FUNCTION TABLE (each gate)

INPUTS		OUTPUT
A	B	Y
H	X	L
X	H	L
L	L	H

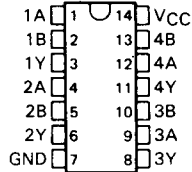
## logic symbol†



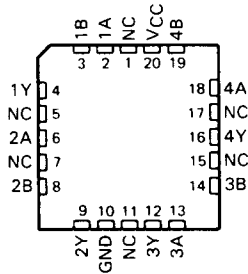
†This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, and N packages.

SN54HC36 . . . J PACKAGE  
SN74HC36 . . . D OR N PACKAGE  
(TOP VIEW)



SN54HC36 . . . FK PACKAGE  
(TOP VIEW)



NC—No internal connection

## logic diagram (positive logic)



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# SN54HC36, SN74HC36 QUADRUPLE 2-INPUT POSITIVE-NOR GATES

## absolute maximum ratings over operating free-air temperature range†

Supply voltage, $V_{CC}$ .....	-0.5 V to 7 V
Input clamp current, $I_{IK}(V_I < 0 \text{ or } V_I > V_{CC})$ .....	$\pm 20$ mA
Output clamp current, $I_{OK}(V_O < 0 \text{ or } V_O > V_{CC})$ .....	$\pm 20$ mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$ .....	$\pm 25$ mA
Continuous current through $V_{CC}$ or GND pins .....	$\pm 50$ mA
Lead temperature 1,6 mm (1/16 in) from case for 60 s: FK or J package .....	300°C
Lead temperature 1,6 mm (1/16 in) from case for 10 s: D or N package .....	260°C
Storage temperature range .....	-65°C to 150°C

†Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions

		SN54HC36			SN74HC36			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
$V_{CC}$	Supply voltage	2	5	6	2	5	6	V
$V_{IH}$	High-level input voltage	$V_{CC} = 2$ V	1.5		1.5			V
		$V_{CC} = 4.5$ V	3.15		3.15			
		$V_{CC} = 6$ V	4.2		4.2			
$V_{IL}$	Low-level input voltage	$V_{CC} = 2$ V	0	0.3	0	0.3		V
		$V_{CC} = 4.5$ V	0	0.9	0	0.9		
		$V_{CC} = 6$ V	0	1.2	0	1.2		
$V_I$	Input voltage	0	$V_{CC}$		0	$V_{CC}$		V
$V_O$	Output voltage	0	$V_{CC}$		0	$V_{CC}$		V
$t_t$	Input transition (rise and fall) times	$V_{CC} = 2$ V	0	1000	0	1000		ns
		$V_{CC} = 4.5$ V	0	500	0	500		
		$V_{CC} = 6$ V	0	400	0	400		
$T_A$	Operating free-air temperature	-55		125	-40		85	°C

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CC}$	$T_A = 25^\circ\text{C}$			SN54HC36		SN74HC36		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$V_{OH}$	$V_I = V_{IH} \text{ or } V_{IL}, I_{OH} = -20 \mu\text{A}$	2 V	1.9	1.998		1.9	1.9		V	
		4.5 V	4.4	4.499		4.4	4.4			
		6 V	5.9	5.999		5.9	5.9			
$V_{OL}$	$V_I = V_{IH} \text{ or } V_{IL}, I_{OL} = 20 \mu\text{A}$	2 V		0.002	0.1		0.1	0.1	V	
		4.5 V		0.001	0.1		0.1	0.1		
		6 V		0.001	0.1		0.1	0.1		
$V_{OL}$	$V_I = V_{IH} \text{ or } V_{IL}, I_{OL} = 4 \text{ mA}$	4.5 V		0.17	0.26		0.4	0.33	V	
		6 V		0.15	0.26		0.4	0.33		
		6 V		0.15	0.26		0.4	0.33		
$I_I$	$V_I = V_{CC} \text{ or } 0$	6 V	$\pm 0.1$		$\pm 100$	$\pm 1000$		$\pm 1000$	nA	
$I_{CC}$	$V_I = V_{CC} \text{ or } 0, I_O = 0$	6 V			2	40		20	$\mu\text{A}$	
$C_i$		2 to 6 V	3		10	10		10	pF	

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted),  $C_L = 50$  pF (see Note 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	T <sub>A</sub> = 25°C			SN54HC36		SN74HC36		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	2 V	50	110	150	125	ns			
			4.5 V	10	20	30	25				
			6 V	8	17	25	21				
t <sub>t</sub>		Y	2 V	38	75	110	95	ns			
			4.5 V	8	15	22	19				
			6 V	6	13	19	16				

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C <sub>pd</sub>	Power dissipation capacitance per gate	No load, T <sub>A</sub> = 25°C	20 pF typ
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NOTE 1: Load circuit and voltage waveforms are shown in Section 1.